


FS5ASJ-3

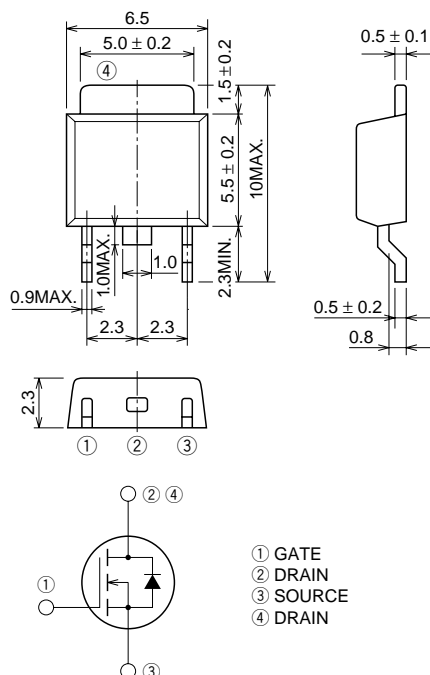
HIGH-SPEED SWITCHING USE

FS5ASJ-3



- 4V DRIVE
- V_{DSS} 150V
- $r_{DS(ON)}(MAX)$ 0.35Ω
- I_D 5A
- Integrated Fast Recovery Diode (TYP.) 85ns

OUTLINE DRAWING Dimensions in mm



① GATE
② DRAIN
③ SOURCE
④ DRAIN

MP-3

APPLICATION

Motor control, Lamp control, Solenoid control
DC-DC converter, etc.

MAXIMUM RATINGS (Tc = 25°C)

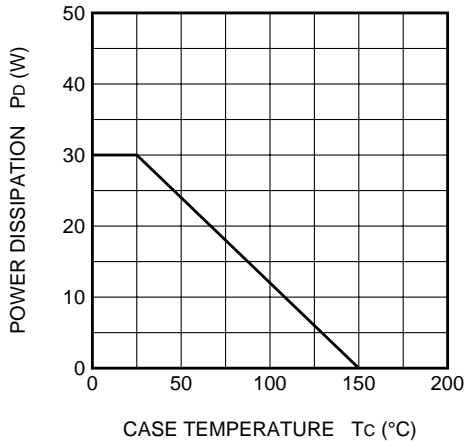
Symbol	Parameter	Conditions	Ratings	Unit
V_{DSS}	Drain-source voltage	$V_{GS} = 0V$	150	V
V_{GSS}	Gate-source voltage	$V_{DS} = 0V$	± 20	V
I_D	Drain current		5	A
I_{DM}	Drain current (Pulsed)		20	A
I_{DA}	Avalanche drain current (Pulsed)	$L = 100\mu H$	5	A
I_S	Source current		5	A
I_{SM}	Source current (Pulsed)		20	A
P_D	Maximum power dissipation		30	W
T_{ch}	Channel temperature		-55 ~ +150	°C
T_{stg}	Storage temperature		-55 ~ +150	°C
—	Weight	Typical value	0.26	g

ELECTRICAL CHARACTERISTICS (Tch = 25°C)

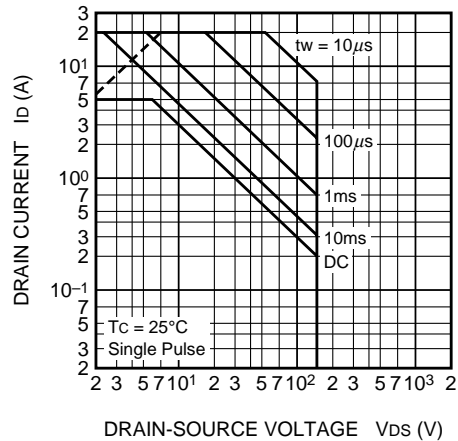
Symbol	Parameter	Test conditions	Limits			Unit
			Min.	Typ.	Max.	
V (BR) DSS	Drain-source breakdown voltage	ID = 1mA, VGS = 0V	150	—	—	V
IGSS	Gate-source leakage current	VGS = ±20V, VDS = 0V	—	—	±0.1	μA
IDSS	Drain-source leakage current	VDS = 150V, VGS = 0V	—	—	0.1	mA
VGS (th)	Gate-source threshold voltage	ID = 1mA, VDS = 10V	1.0	1.5	2.0	V
rDS (ON)	Drain-source on-state resistance	ID = 2A, VGS = 10V	—	0.27	0.35	Ω
rDS (ON)	Drain-source on-state resistance	ID = 2A, VGS = 4V	—	0.28	0.37	Ω
VDS (ON)	Drain-source on-state voltage	ID = 2A, VGS = 10V	—	0.54	0.70	V
yfs	Forward transfer admittance	ID = 2A, VDS = 5V	—	9.5	—	S
Ciss	Input capacitance	VDS = 10V, VGS = 0V, f = 1MHz	—	800	—	pF
Coss	Output capacitance		—	100	—	pF
Crss	Reverse transfer capacitance		—	35	—	pF
td (on)	Turn-on delay time	VDD = 80V, ID = 2A, VGS = 10V, RGEN = RGS = 50Ω	—	14	—	ns
tr	Rise time		—	17	—	ns
td (off)	Turn-off delay time		—	65	—	ns
tf	Fall time		—	31	—	ns
VSD	Source-drain voltage	IS = 2A, VGS = 0V	—	1.0	1.5	V
Rth (ch-c)	Thermal resistance	Channel to case	—	—	4.17	°C/W
trr	Reverse recovery time	IS = 5A, dis/dt = -100A/μs	—	85	—	ns

PERFORMANCE CURVES

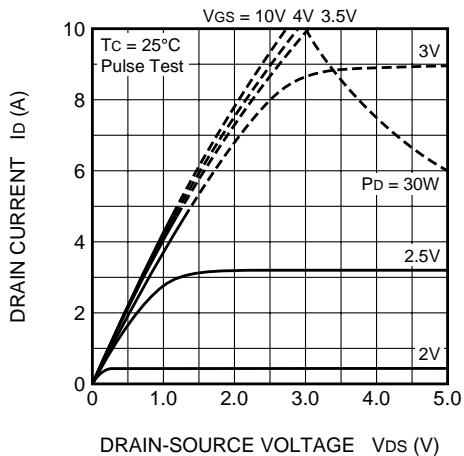
POWER DISSIPATION DERATING CURVE



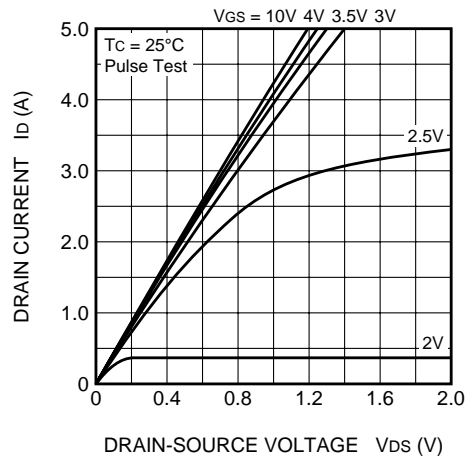
MAXIMUM SAFE OPERATING AREA



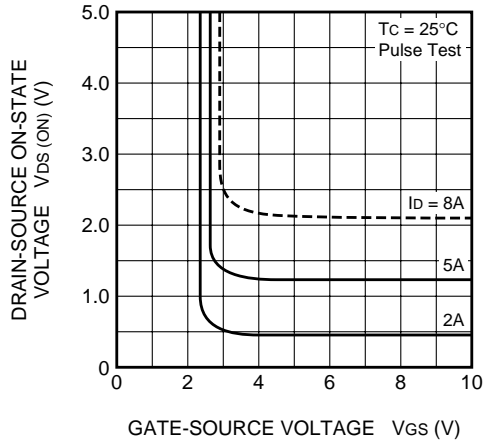
OUTPUT CHARACTERISTICS (TYPICAL)



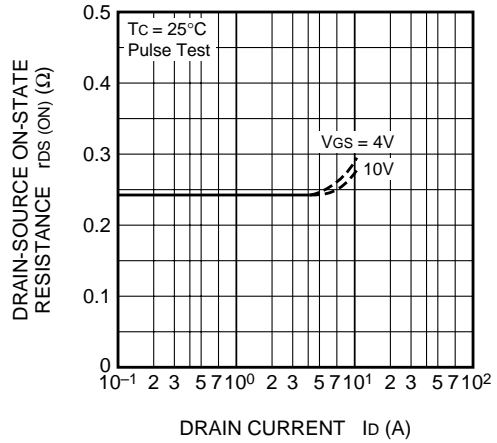
OUTPUT CHARACTERISTICS (TYPICAL)



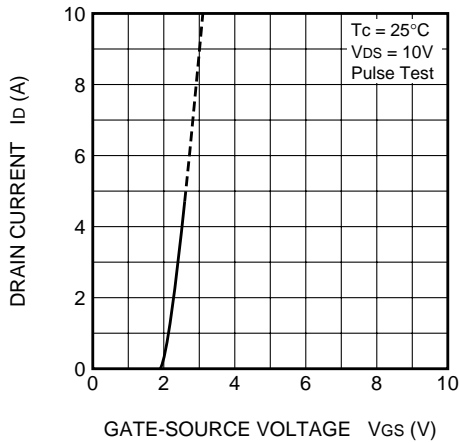
ON-STATE VOLTAGE VS. GATE-SOURCE VOLTAGE (TYPICAL)



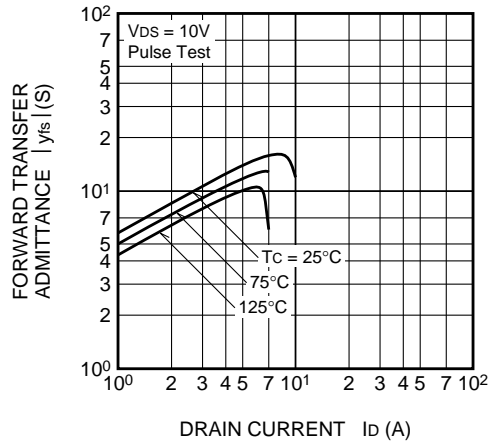
ON-STATE RESISTANCE VS. DRAIN CURRENT (TYPICAL)



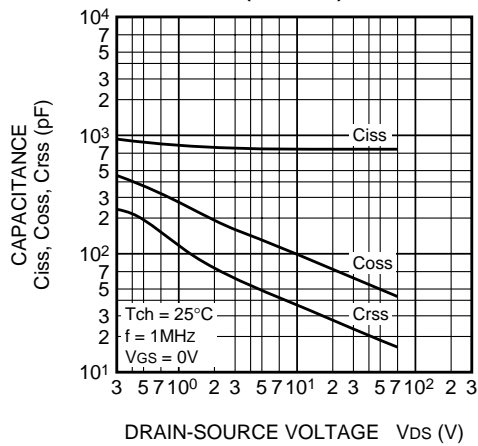
TRANSFER CHARACTERISTICS (TYPICAL)



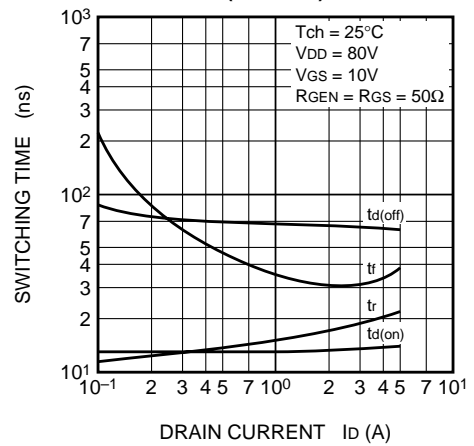
FORWARD TRANSFER ADMITTANCE VS. DRAIN CURRENT (TYPICAL)



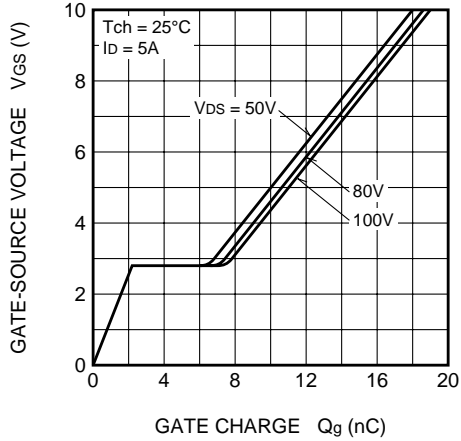
CAPACITANCE VS. DRAIN-SOURCE VOLTAGE (TYPICAL)



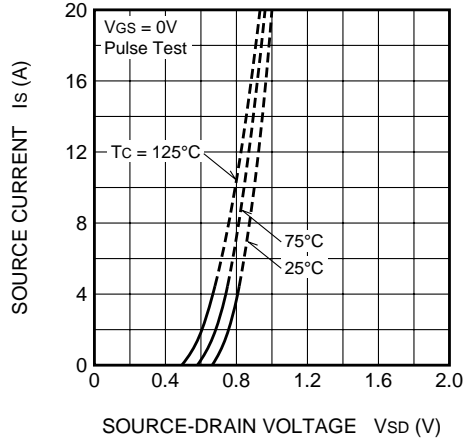
SWITCHING CHARACTERISTICS (TYPICAL)



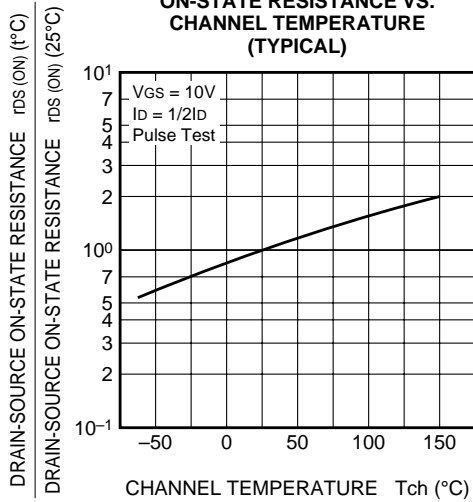
GATE-SOURCE VOLTAGE VS. GATE CHARGE (TYPICAL)



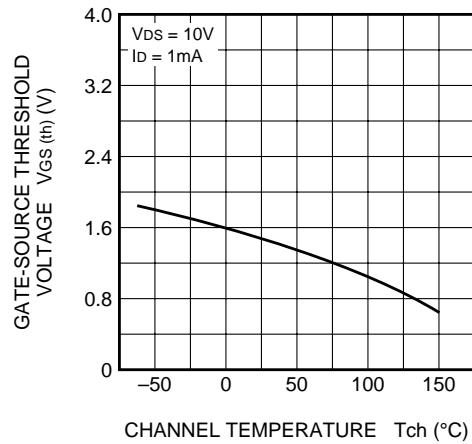
SOURCE-DRAIN DIODE FORWARD CHARACTERISTICS (TYPICAL)



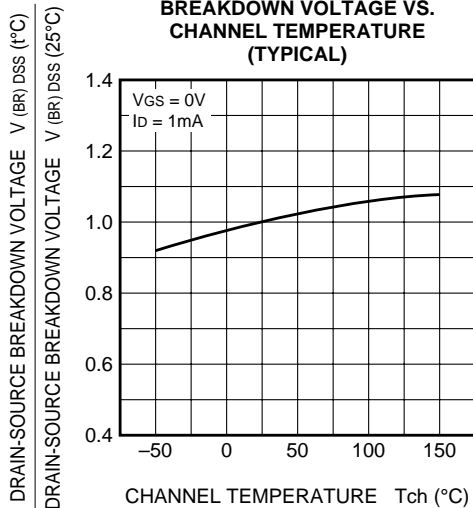
ON-STATE RESISTANCE VS. CHANNEL TEMPERATURE (TYPICAL)



THRESHOLD VOLTAGE VS. CHANNEL TEMPERATURE (TYPICAL)



BREAKDOWN VOLTAGE VS. CHANNEL TEMPERATURE (TYPICAL)



TRANSIENT THERMAL IMPEDANCE CHARACTERISTICS

